

Quantum interference and nonequilibrium Josephson current in molecular Andreev interferometers

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We study the quantum interference (QI) effects in three-terminal Andreev interferometers based on polyaromatic hydrocarbons (PAH's) under non-equilibrium conditions. The Andreev interferometer consists of a PAH coupled to two superconducting and one normal conducting terminals. We calculate the current measured in the normal lead as well as the current between the superconducting terminals under non-equilibrium conditions. We show that both the QI arising in the PAH cores and the bias voltage applied to a normal contact have a fundamental effect on the charge distribution associated with the Andreev Bound States (ABS's). QI can lead to a peculiar dependence of the normal current on the superconducting phase difference that was not observed in earlier studies of mesoscopic Andreev interferometers. We explain our results by an induced asymmetry in the spatial distribution of the electron- and hole-like quasiparticles. The non-equilibrium charge occupation induced in the central PAH core can result in a π transition in the current-phase relation of the supercurrent for large enough applied bias voltage on the normal lead. The asymmetry in the spatial distribution of the electron- and hole-like quasiparticles might be used to split Cooper pairs and hence to produce entangled electrons in four terminal setups.

INTRODUCTION

Quantum interference (QI) is ubiquitous in nature. Constructive quantum interference (CQI) leads to the formation of energy levels in atoms or molecules and energy bands in crystals, whereas destructive quantum interference (DQI) leads to energy gaps in molecules and band gaps in solids. The energy scale for these QI phenomena can be up to a few eV and therefore these quantum effects control the properties of molecules and solids at room temperature, for which $k_B T \approx 25 meV \ll 1 eV$. In addition to these high temperature manifestations of QI, many low-temperature interference phenomena are well known, such as superfluidity and superconductivity, which occur on energy scale of order a few meV or less.

Investigations of QI in condensed systems are often driven by the desire to harness QI and deliver useful function. For example, when a molecule is placed into the nanogap between two metallic electrodes, it is known that electron transport from the source to the drain electrode is phase coherent at room temperature, provided the length of the molecule is less than approximately $3 nm$. Consequently, if the interference pattern created by electronic de Broglie waves passing through the molecule can be controlled, then useful room-temperature devices such as molecular-scale switches, transistors and sensors could be realised. Single-molecule electronics is the sub-field of nanoelectronics^{1–7}, which aims to deliver such structures and in pursuing this goal, many groups have demonstrated that electrons can be injected into (and collected from) the core of a molecule with atomic accuracy^{8–11}. Furthermore, it has been demonstrated that an ability to vary the atomic-scale connectivity to molecular cores is an effective way of controlling room-temperature QI^{12,13}. On the other hand, at lower temperatures, quantum engineers strive to utilise QI in superconducting structures

such as SQUIDS and Andreev interferometers, which rely on controlling the interplay between a superconducting condensate and charge-carrying quasi-particles^{14–22}. In such devices, QI is controlled by the phase of the superconducting order parameter, which describes a macroscopic collective degree of freedom, which has no counterpart at room temperature.

In this article, we examine the interplay between the high-energy-scale QI found in molecules and the low-temperature QI present in superconductors. Our aim is to determine how an ability to control the connectivity to molecular cores with atomic accuracy can be used to engineer the properties of Andreev interferometers and SQUIDS.

From the viewpoint of connectivity, a fundamental manifestation of QI is illustrated in Fig. 1 top and middle panels, which shows an anthanthrene molecular core (consisting of 6 six-membered rings) connected by triple bonds to external electrodes. The connectivity of the triple bonds to the core is fixed by chemical synthesis. Fig. 1 shows two examples of molecules with different connectivities. Following the numbering scheme of the lattice shown at the bottom of Fig. 1, molecule 1 has triple bonds connected to atoms 12 and 3, whereas molecule 2 has triple bonds connected to atoms 9 and 22. The triple bonds are connected to terminal aryl rings, which in turn are connected to thioacetate anchor groups, which bind the molecules to source and drain electrodes. Since the triple bonds form weak links to the central core, it is conceptually convenient to consider the combination of an aryl ring, anchor group and external electrode as a single “compound electrode”, (coloured blue in Fig. 1) which injects or collects electrons to or from the central core, via the triple bonds. Remarkably, when the external electrodes are normal (i.e., not superconducting), the room-temperature electrical conductance of setup 1 is both measured and predicted to be almost two orders

of magnitude higher than that of 2. This is a clear manifestation of room-temperature QI, since the conductance of a corresponding classical resistor network formed from six rings of resistors would show a much lower dependence on connectivity. From the viewpoint of superconductivity, our aim is to replace one or more of the normal electrodes by superconducting electrodes and examine how electron transport through such molecular cores is controlled by a combination of connectivity and by the phase of the superconducting order parameter.

In ballistic normal-superconductor (N-S) hybrid systems the fundamental transport process is Andreev reflection, whereby an incoming electron is reflected back as a hole at the N-S interface. A rich set of physical phenomena that follow from this scattering process was realized in Andreev interferometers, which are devices with two (or more) superconducting and one (or more) normal leads attached to a central region^{14,15}. For example, due to the extraordinary sensitivity of the Andreev current to the superconducting phase difference, Andreev interferometers may provide a faster and more precise alternative to superconductor quantum interference devices (SQUIDS)¹⁶ to measure properties of quantum systems or even detecting Majorana bound states¹⁷. Importantly, the presence of a normal lead allows one to change the equilibrium occupation of Andreev bound states formed in multi-terminal N-S systems. It was suggested that such a non-equilibrium effect can be used to engineer π -Josephson junctions^{18,19}, where the fundamental relation $I_s = I_c \sin(\delta\phi)$ between the phase difference $\delta\phi$ of the order parameters of two superconductors and the supercurrent I_s can be changed to $I_s = I_c \sin(\delta\phi + \pi)$ (I_c is the critical current). This effect has indeed been measured in diffusive meso-scopic multi-terminal N-S systems^{20–22}.

Recently, the superconducting properties of molecular-scale junctions have also started to attract experimental^{23–26} as well as theoretical^{27–29} interest. In Ref.²⁹ we discussed the equilibrium properties of various multiterminal N-S systems where, in particular, QI effects in the core of the molecule play an important role. Here we show how such QI effects and non-equilibrium charge injection can lead to interesting effects in molecular Andreev interferometers. Namely, the non-equilibrium occupation of the Andreev bound states (ABS's) which are formed in superconductor-molecule-superconductor (S-M-S') Josephson junctions can be driven via the third, normal lead attached to the Josephson junction, thus realizing a non-equilibrium N-M-SS' system. As already mentioned, one of the key ingredients in our work is QI which arises in the molecular core of N-M-SS' systems that are based on PAHs^{12,13,30}. We find that in these systems one may observe effects that were not attainable in previously studied mesoscopic Andreev interferometers. Based on the “magic number theory of connectivity in Refs.^{12,29,30} we show that conductive channels through the molecular core can give rise to interfering paths contributing to the total ABS wave function with the same or with

an opposite sign for electron and hole-like degrees of freedom. This rich set of interfering paths is provided by the conductive channels opened by the insertion of a substituent heteroatom into the molecular core¹³. Under specific circumstances the interplay of the interfering amplitudes may even lead to the total suppression of the electron-like (or hole-like) degrees of freedom on certain molecular sites and, at the same time, to a constructive interference for the hole-like (or electron-like) charge carriers. Since the charge current through the normal lead is closely tied to the Andreev reflection process, its magnitude is highly influenced by the density of both the electron- and hole-like particles in the vicinity of the normal contact. Thus, by measuring the charge current through the normal lead one can also probe the electron-hole separation in the molecular junction.

In what follows, we first describe the main characteristics of interference effects in Andreev interferometers based on PAHs^{12,13,30} in equilibrium conditions. Our choice is justified by the peculiar mid-gap transport properties of these molecules accompanied by inner quantum interference effects within the core of the molecule^{12,13,29,31–42}. We outline an illustrative connectivity-based theory that can be used to understand the current-phase relations at non-equilibrium conditions as well. Then we present our numerical results obtained for the normal and for the supercurrent at finite bias applied on the normal lead. We interpret our results in terms of connectivity arguments. We examine how the electrical properties of the Andreev interferometers would be influenced by tuning the inner QI effects of the molecular core. We demonstrate how QI can lead to a suppression of the normal current which is a clear evidence of the spatial separation of the electron- and hole-like particles. Finally, we present a summary of our most important results and give a brief outlook.

THEORETICAL BACKGROUND: EQUILIBRIUM MOLECULAR ANDREEV INTERFEROMETERS

From a conceptual viewpoint the key ingredients of our theoretical model are based on weak coupling, connectivity-driven, mid-gap transport and phase coherence. A detailed explanation of these assumptions is given in Refs.^{12,29,30}. Here we only mention that the term “weak coupling” means that the central aromatic molecule is weakly coupled to the contacts resulting in a small level broadening and self energy correction to the HOMO and LUMO levels compared to the HOMO-LUMO gap. Thus, provided the Fermi level lies within the gap (resulting in near mid-gap transport), the quantum interference effects in the phase coherent transport processes are characterized by the properties of the molecular core alone. (The Coulomb interactions can be included at the level of a self-consistent mean field description such as Hartree, or Hartree-Fock.) Taken together, these conditions ensure that when computing

the Green's function of the core, the contribution of the electrodes can be ignored. Consequently, the probability of the propagation of the charged particles between sites k and l of the molecule is described by the “magic number” matrix element^{12,29,30} $M_{kl} \sim g_{kl}$, where $g(E_F) = (E_F - H_{\text{mol}})^{-1}$ is the Green's function of the isolated molecule described by Hamiltonian H_{mol} . In particular, the electrical conductance corresponding to connectivity k, l is proportional to $|M_{kl}|^2$. In the simplest theoretical description an integer valued connectivity matrix H_{mol} captures the complexity of the inner CQI and DQI effects within the core of the molecule and when E_F coincides with the middle of the HOMO-LUMO gap, the resulting magic number matrix M_{kl} is simply a table of integers. In particular, for the bipartite lattice of Fig. 1, when E_F coincides with the middle of the HOMO-LUMO gap, destructive quantum interference arises between sites k and l that have the same parity (i.e., both are odd or both are even) and therefore the matrix element M_{kl} is zero. In contrast, when the sites k and l have different parity, M_{kl} may be finite giving a non-zero propagation amplitude of the charged particles between sites k and l . For the anthanthrene core of Fig. 1, $M_{3,12} = 1$ and $M_{9,22} = 9$. Hence their conductance ratio is predicted to be $|M_{9,22}|^2/|M_{3,12}|^2 = 81$, which is close to the measured value of the conductance ratio, both for single molecules and for self-assembled monolayers^{12,30,43}.

In order to understand the unconventional non-equilibrium Andreev interference effect described in the next sections, following Ref.²⁹ we first give a brief overview of the considerations that explain the interference pattern in the current I_N flowing through the normal lead as a function of the superconducting phase difference $\delta\phi = \phi_1 - \phi_2$ between the S1 and S2 leads (see Fig. 1) in equilibrium. Under equilibrium conditions, the limit $eV \rightarrow 0$ is understood, where V is the applied bias on lead N with respect to the chemical potential of the superconductors. Note that the imposition of a phase difference $\delta\phi$ also generates a Josephson current I_s flowing between the superconducting leads. Experimentally, as shown in Refs^{44,45}, $\delta\phi$ can be controlled, thus allowing the measurement of the current-phase relation (CPR) of the supercurrent I_s and the phase dependence of I_N .

Let us investigate I_N in a device consisting of an anthanthrene central molecular core, as shown in Fig. 1. The $\delta\phi$ dependence of I_N can be understood as a result of an interference effect between the possible transport paths of electrons and holes. The arms of the interferometer are formed by the trajectories $N \rightarrow \text{mol} \rightarrow \text{S1} \rightarrow \text{mol} \rightarrow \text{N}$ and $N \rightarrow \text{mol} \rightarrow \text{S2} \rightarrow \text{mol} \rightarrow \text{N}$. Let us consider the setup in which the normal lead N is attached to site labeled by 22, and the superconducting leads S1 and S2 are attached to sites 9 and 15, respectively and examine the transmission amplitude $t_{9,22}$ related to the process $N \rightarrow \text{mol} \rightarrow \text{S1} \rightarrow \text{mol} \rightarrow \text{N}$. Since the normal reflection on the superconductors does not give a contribution to the charge current, only Andreev reflection⁴⁶ can cause a net charge current. During

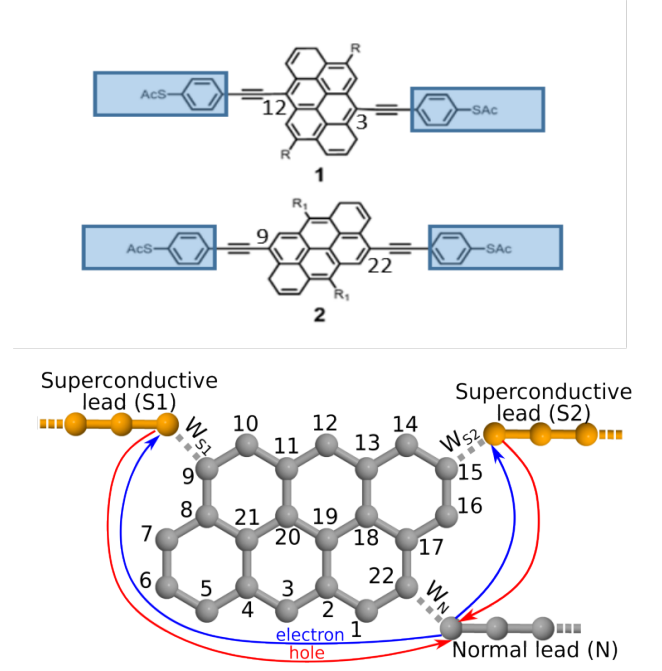


Figure 1. The top and middle panels show molecules 1 and 2, with connectivities 12, 3 and 9, 22 to the anthanthrene molecular core. The lower panel shows an Andreev interferometer consisting of an anthanthrene molecule, two superconducting leads and one normal lead. The “sites” of the associated tight-binding model represent p_z orbitals of the anthanthrene molecule and are labelled according to the figure. The coupling of the molecule to the normal (superconducting) lead is denoted by W_N (W_S), for details see the text. The superconducting leads are characterized by a superconducting order parameter $\Delta e^{i\phi_1}$ and $\Delta e^{i\phi_2}$. The transport processes responsible for the conventional interference effect are indicated by solid lines for the electron-like (blue) and hole-like (red) propagation.

Andreev reflection, an incoming electron-like quasiparticle is converted into a hole-like quasiparticle and vice versa at the normal-superconductor interface. Due to the Andreev reflection, an extra $e^{-i\phi_1}$ phase factor multiplies the transmission amplitude (ϕ_1 is the phase of the superconductor S1). Then, the reflected hole-like state propagates back to the normal lead, a process which can be described by $-M_{9,22}$ according to the Bogoliubov-de Gennes equation²⁹. Based on these considerations, the transmission amplitude can be written in the following form:

$$t_{9,22} \sim -M_{9,22}^2 e^{-i\phi_1}. \quad (1)$$

Similar considerations can be made for the transmission amplitude $t_{15,22}$. Since there are two interfering arms in the interferometer, one needs to sum up both transmission amplitudes associated with the two propagation paths to calculate the total transmission amplitude:

$$t_{\text{tot}} \sim t_{9,22} + t_{15,22} = -M_{9,22}^2 e^{-i\phi_1} - M_{15,22}^2 e^{-i\phi_2}, \quad (2)$$

From this expression the Andreev current I_N at small bias voltage ($eV \ll \Delta$) can be approximated as:

$$I_N \sim |t_{tot}|^2 = M_{9,22}^4 + M_{15,22}^4 + 2 \cdot M_{9,22}^2 \cdot M_{15,22}^2 \cdot \cos(\phi_1 - \phi_2). \quad (3)$$

As one can see, the Andreev current I_N is indeed expected to show a simple dependence on the superconducting phase difference $\delta\phi = \phi_1 - \phi_2$ with a minimum at π . Regarding the supercurrent I_s flowing between S1 and S2, in first approximation, this can be understood as a consequence of Andreev bound states (ABS), although a continuum of unbound states can also add a finite contribution⁴⁷.

NON-EQUILIBRIUM NUMERICAL CALCULATIONS

To avoid time-dependent order parameter phases varying at the Josephson frequency, we assume that the superconductors S1 and S2 share a common condensate chemical potential μ . A finite bias voltage V (with respect to μ) can be then applied to the normal lead. This bias voltage will affect both the normal current I_N and, by changing the equilibrium occupation of the ABSs, the supercurrent I_s as well.

In order to describe the transport properties at finite bias voltage one has to use a theoretical framework capable of describing non-equilibrium transport processes. We calculate the currents I_N and $I_s = (I_{S1} - I_{S2})/2$ by using a tight binding approach and the Keldysh non-equilibrium Green's function techniques^{48–50}:

$$I_{N(S_i)} = -\frac{2e}{h} \text{Re} \left[\int dE \text{Tr} (\tau_3 \Gamma_{N(S_i)} G^<(E)) \right], \quad (4)$$

with $\Gamma_{N(S_i)}$ being the coupling from the molecule to the normal (superconducting) lead labeled by N (S_i) including the electron-hole degrees of freedom and τ_3 is the third Pauli matrix acting on the electron-hole space. The current $I_{N(S_i)}$ describes the current flowing through lead N (S_i) into the central molecule. In the steady state limit the currents flowing through the individual leads satisfy the charge conservation rule $I_N + I_{S1} + I_{S2} = 0$ leading to two independent currents I_N and I_s characterizing the electrical properties of the junction. Finally, the lesser Green's function $G^<$ in Eq.(4) can be calculated within the Keldysh non-equilibrium framework using the tight-binding framework implemented in the EQUUS⁵¹ package. The relevant electronic states in the molecular core were described by a single orbital tight-binding model where the nearest neighbor sites are connected by a hopping amplitude γ_0 . As shown in Fig. 1, the hopping amplitude between the molecule and the normal N (superconducting S1, S2) lead is given by W_N (W_{S1} , W_{S2}). In our calculations, unless indicated otherwise, we used $W_N = 0.1\gamma_0$ and $W_S = 0.3\gamma_0$. The

normal and superconducting contacts were modeled by a one-dimensional tight-binding chain. The magnitude of the superconducting order parameter in the leads S1 and S2 was $\Delta = 3 \cdot 10^{-3}\gamma_0$. The results that we are going to discuss do not depend on the actual value of γ_0 and Δ . This simple model is justified by previous studies of connectivity driven transport processes through PAH molecules^{12,29,30}. Following these works, our aim is to highlight the role of connectivity in the transport properties of these molecular cores leading to new interference phenomena. We give the remaining details of the tight binding-model used in our calculations in the electronic supplementary material.

NON-EQUILIBRIUM MOLECULAR ANDREEV INTERFEROMETERS

As a first example of non-equilibrium effects in Andreev-interferometers it is instructive to consider the system shown in Fig.2. With respect to Fig. 1, we changed the connecting sites of the leads in order to “disarm” one of the interfering arms. This can be achieved by choosing connecting sites such that the magic number matrix elements between the sites connected to the normal lead and to one of the superconducting leads becomes zero, as shown in Fig. 2. Therefore one may expect I_N to be independent of the superconducting phase. Note, however, that the magic number $M_{6,9}$ between the superconducting leads is finite. Therefore, as we will show later, an ABSs is formed in this system and it has an important effect on I_N . The results for $\delta\phi$ and eV dependence of I_N can be seen in Fig.3(a). The current I_N remains very small for applied voltages $eV \ll \Delta$ on the normal lead. As eV is increased, a finite I_N starts to flow, but in contrast to the $\sim \cos \delta\phi$ dependence given in Eq(3), I_N exhibits a *maximum* at superconducting phase difference $\delta\phi = \pi$.

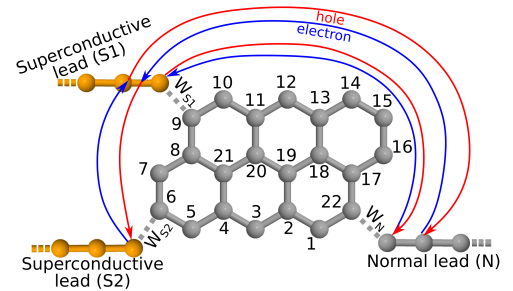


Figure 2. Anthracene molecule attached to two superconductive and one normal lead. The connectivity matrix element between the sites 6 and 22 is zero, while the connectivity between sites 9 and 22 and between sites 9 and 6 is finite. Solid lines indicate the propagation of the electron-like (blue) and hole-like (red) quasiparticles.

These results can be explained by the effect of an ABS. As pointed out in earlier studies on multitermi-

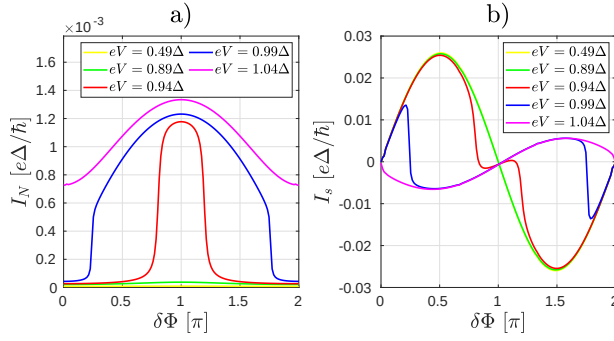


Figure 3. The currents I_N (a) and I_s (b) as a function of the phase difference $\delta\phi$ between the superconducting leads for the system depicted in Fig. 2 for several bias voltage eV . a) a robust peak in I_N appears around the phase difference π when the bias voltage is comparable to the superconducting gap Δ . b) the supercurrent shows a π transition for $eV > \Delta$.

nal normal-superconductor mesoscopic systems^{18,19}, the voltage eV sets the effective electrochemical potential for the ABSs and those with energy $E_{n,ABS}(\delta\phi) \leq eV$ are filled. The ABS energy $E_{n,ABS}(\delta\phi)$ depends on the phase difference $\delta\phi$. A change in the occupation of the ABSs directly affects I_{S1} and I_{S2} and therefore the current distribution in the Andreev-interferometer junction will depend on both the voltage eV and on the phase difference $\delta\phi$. To illustrate these effects we show the supercurrent $I_s = (I_{S1} - I_{S2})/2$ in Fig3(b). As eV is increased, a deviation from the simple $I_s = I_c \sin(\delta\phi)$ relation can be clearly seen and for $eV > \Delta$ a π -transition takes place in I_s , similarly to what was obtained in Refs.^{18,19}.

One can give a heuristic argument of why the presence of ABSs can affect I_N . This argument draws on analogies with the discussion given for the equilibrium case, i.e., it is based on interfering quasiparticle trajectories. Although in the system depicted in Fig.2 the connectivity between the normal lead and the superconducting lead $S2$ is zero, the charge carriers can still probe the phase of lead $S2$ when they propagate along a path that also includes an Andreev reflection from the lead $S1$. Namely, as illustrated in Fig. 2, both $M_{22,9}$ and $M_{6,9}$ are finite. We denote the amplitude of such propagation by $t_{6,22}^{(9)}$, where the upper index (9) indicates that the propagation between the sites 6 and 22 takes place via site the 9. To approximate the amplitude $t_{6,22}^{(9)}$ one can make similar considerations as in the previous section. Thus,

$$t_{6,22}^{(9)} \sim (-M_{22,9}) \cdot e^{-i\phi_1} \cdot M_{9,6} \cdot e^{i\phi_2} \cdot (-M_{6,9}) \cdot e^{-i\phi_1} \cdot M_{9,22}. \quad (5)$$

This amplitude describes a (a) propagation from the normal lead to the superconducting electrode $S1$ ($M_{9,22}$), (b) Andreev reflection from electrode $S1$ ($e^{-i\phi_1}$), (c) propagation of the hole-like state from contact $S1$ to $S2$ ($-M_{6,9}$), (d) Andreev reflection of the hole-like particle on the contact $S2$ ($e^{i\phi_2}$), (e) electron-like propagation between the superconducting electrodes $S1$ and $S2$ ($M_{9,6}$),

(f) a third Andreev reflection on the superconducting electrode $S1$ ($e^{-i\phi_1}$), (g) and a hole-like propagation from the contact $S1$ to the normal lead ($-M_{22,9}$). Finally, we also take into account in our minimal model the amplitude $t_{9,22}$ describing the direct propagation between the normal lead and the lead $S1$ according to Eq.(1). The observed interference effect can be explained as the interplay between these two amplitudes:

$$I_N \sim |t_{9,22} + t_{6,22}^{(9)}|^2 = M_{9,22}^4 \cdot (1 + M_{9,6}^4 - 2 \cdot M_{9,6}^2 \cdot \cos(\phi_1 - \phi_2)) \quad (6)$$

The normal current I_N in Eq(6) has a maximum at phase difference $\phi_1 - \phi_2 = \pi$. The minus sign appearing in front of the $\cos(\phi_1 - \phi_2)$ term in Eq(6) is due to the peculiar properties of the Bogolioubov-de Gennes quasiparticles. Namely, the amplitude $t_{6,22}^{(9)}$ contains one more hole-like propagation compared to the amplitude $t_{9,22}$, which brings in an extra minus sign needed for the formation of the unconventional interference effect. Note, that this argument does not explain why the increase in I_N appears only above a certain bias voltage. Moreover, the transport process associated to the amplitude $t_{6,22}^{(9)}$ contains four more tunnelings between the superconducting leads and the molecular core compared to the amplitude $t_{9,22}$. Thus, the amplitude $t_{9,22}$ might be expected to be much larger than the amplitude $t_{6,22}^{(9)}$ which would suppress the interference effect between these two interfering paths.

The role of the ABSs can be shown explicitly by using Green's function theory to calculate the differential conductance $\frac{dI_N}{deV}$. The details of this calculation are presented in the electronic supplementary information. For simplicity, let us assume that there is only one ABS in the system (the general case of more than one ABS is discussed in the electronic supplementary). Then the differential conductance can be approximated as⁵²

$$\frac{dI_N}{deV} \approx \frac{16e}{h} \frac{\Gamma_{ABS,e} \Gamma_{ABS,h}}{(eV - E_{ABS})^2 + \Gamma_{ABS}^2}, \quad (7)$$

where $\Gamma_n = \Gamma_n^e + \Gamma_n^h$ is the level broadening of the ABS due to the presence of the normal lead, $\Gamma_{ABS,e} = \langle ABS, e | W_N^\dagger \text{Im}(g_N^e) W_N | ABS, e \rangle$ with W_N being the coupling between the normal lead and the central molecule, g_N^e standing for the electron-like block of the surface Green's function of the normal contact evaluated at energy E_{ABS} , and $|ABS, e\rangle$ represents the electron-like components of the wave function of the ABS. The definition of $\Gamma_{ABS,h}$ is analogous to $\Gamma_{ABS,e}$ involving the hole-like degrees of freedom instead of the electron-like components. According to Eq(7), the ABS leads to a resonant peak of Lorentzian lineshape in the differential conductance for $eV \approx E_{ABS}(\delta\phi)$. The half-width of the resonance is determined by the finite lifetime of the ABS which is due to the coupling to the normal lead given by $\Gamma_{ABS,e}$ and $\Gamma_{ABS,h}$. We note that a similar result can be obtained for a system hosting multiple ABSs. The total differential conductance in this case would be a sum

of resonances centered on the energies of the individual ABSs'. However, the ‘‘cross-talk’’ between the ABSs has an additional influence on the shape of the resonances, i.e., they start to deviate from the regular Lorentzian shape. (For details see the electronic supplementary material.)

Looking back to Eq. (6), one may now say that the interfering amplitude $t_{6,22}^{(9)}$ can be increased due to the Fabry-Perot-like resonant oscillations of the charged particles between the superconducting contacts. These oscillations lead to the formation of ABSs of finite lifetime, which, in turn, affect the current I_N at finite eV , as indicated by Eq. (7). The ABSs can be visualized by cal-

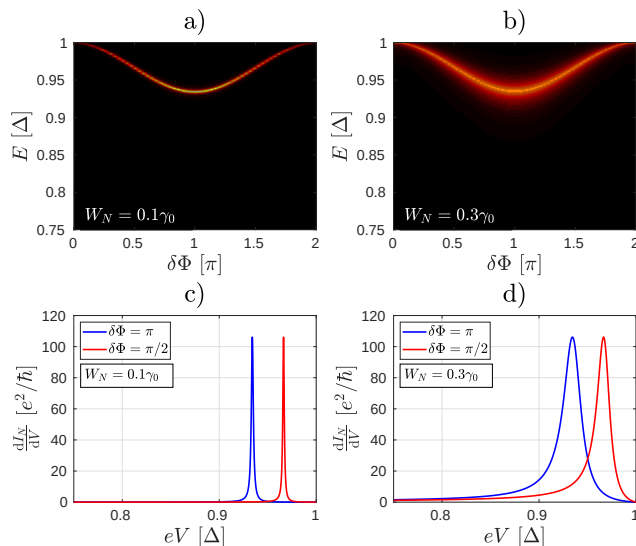


Figure 4. (a) and (b): density of states of the molecular junction shown in Fig. 2 for two different coupling W_N of the normal lead to the molecule. The bright areas indicate the dispersion of the ABS as a function of $\delta\Phi$. The ABS energy level is broadened by increasing W_N . c) A resonance occurs in the differential conductance when the bias voltage eV is close to the energy $E_n(\delta\phi)$ of the ABS in a). d) As the ABS is broadened, the width of the resonance broadens as well.

culating the density of states of the junction (see the electronic supplementary information for details). The results of such calculations for the system in Fig. 2 are shown in Fig. 4. In Figs. 4a) and b) we show the density of states for two different coupling W_N . The large values of the density of states (bright region) indicate the ABS. In this particular case, for $eV = 0$ and zero temperature there is only one occupied ABS (at energy $-E$, not shown) and one unoccupied ABS [at energy E , Figs. 4a) and (b)]. By applying a finite $eV > 0$ the occupation of these ABSs can be changed, leading to the peculiar dependence of both I_N and I_s on $\delta\Phi$ in Fig. 3 that we noted earlier. Because of the normal lead, the ABSs have a finite lifetime, which is determined by the escape rate of the particles through the normal lead. Therefore, the ABS lifetime (and consequently the width of the resonant

peaks in the differential conductance) is expected to be sensitive to the coupling between the normal lead and the central molecule. This can be clearly seen in Fig. 4c) and d), where the peak of the differential conductance calculated for $W_N = 0.1\gamma_0$ is considerably wider than the peak calculated for $W_N = 0.3\gamma_0$. Notice, that for higher values of W_N the resonant peak starts to deviate from the Lorentzian shape. This is because by increasing the coupling between the contacts and the central molecule one can no longer neglect the energy dependence of the Green’s function of the normal contact in the calculation of $\Gamma_{ABS,e}$ and $\Gamma_{ABS,h}$, see the electronic supplementary information. Since the ABS’s energy E_{ABS} depends on the phase difference $\delta\phi$, the peaks in $\frac{dI_N}{deV}$ are also sensitive to the superconducting phase difference. This is also shown in Figs. 4(c) and (d). Therefore, by measuring $\frac{dI_N}{deV}$ as a function of $\delta\phi$ one may obtain spectroscopic information about the ABSs¹⁸.

The role of ABSs and QI in the molecular core can be further illustrated by studying the finite bias properties of the system shown already in Fig. 1, bottom panel. For this configuration of the leads the magic number vanishes between the two sites where the superconducting electrodes are attached. One may therefore expect that there is no ABS present in the system. According to our calculations this is not exactly the case: one can find an ABS whose energy is very close to the value of the pair potential Δ in the leads, but it is nearly independent of $\delta\phi$ and therefore it can carry only a small supercurrent. This explains that for a finite bias eV the $\delta\phi$ dependence of I_N remains qualitatively the same as in the zero bias case discussed in Eqs(1)-(3) and shows a minimum at $\delta\phi = \pi$ for all bias voltages [Fig. 5(a)]. The supercur-

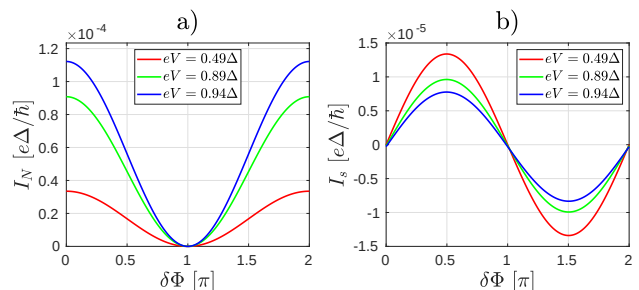


Figure 5. The currents I_N (a) and I_s (b) as a function of the phase difference $\delta\phi$ between the superconducting leads for the system depicted in Fig. 1 for several bias voltage eV . a) the Andreev current I_N shows a minimum at $\delta\phi = \pi$. b) The current-phase dependence of supercurrent is $I_s \propto \sin \delta\phi$.

rent I_s shows the conventional $\propto \sin \delta\phi$ dependence for $eV < \Delta$ [Fig. 5(b)]. By comparing Figs. 5(a) and (b), one can see that although a small I_s can flow for finite eV , the critical current I_c is smaller than I_N . This is the opposite of what we found in the previous case [Fig. 3]. Overall, one may also notice that both I_N and I_c are much smaller than previously, c.f. Figs. 3 and 5.

These results underpin the importance of ABSs in An-

dreev interferometers and are also a consequence of mid-gap transport. Namely, the propagation amplitude described by the Green's function elements decay with the energy difference between the chemical potential and the energy of the eigenstates. Since the energy levels of the molecule are much further from the chemical potential than the ABS levels, their contribution to the Green's function elements will be also much smaller than the contribution of the ABSs. Thus, in the mid-gap energy regime, the transport processes would indeed be dominated by the interference effects related to the ABSs.

We now discuss the most general situation, where ABSs can be found in the system and, in contrast with the case in Fig. 1, the connectivity from the normal lead to both superconducting terminal is finite. In what follows we shall examine the unconventional interference effects as the connectivity in the interferometer is changed. We consider a setup similar to the one shown in Fig. 1 and tune the asymmetry of the molecular interferometer by inserting a substitutional heteroatom into the molecular core¹³, i.e. a carbon atom is replaced by a substituent heteroatom, as indicated schematically in Fig. 6(a). Due to the presence of the heteroatom, new conductive channels open up in the molecular core that were originally closed via destructive QI effects. In our theoretical model we account for the presence of a substitutional heteroatom by a modified on-site energy on a specific site in the molecule. By changing e.g., the on-site energy ε_3 in the tight-binding Hamiltonian of the molecular core [see Fig. 6(a)], the normal conductance between sites labeled by even numbers also becomes finite¹³. Assuming that instead of S1 and S2 we have normal conducting leads N1 and N2 as in Fig. 6(a), the evolution of the ratio of the zero-bias normal conductances $\sigma_{N,N1}$ and $\sigma_{N,N2}$ as a function of the on-site energy ε_3 is demonstrated in Fig. 6(b). As one can see, by varying ε_3 one can gradually open a conductive channel between leads N and N2.

We now consider the finite bias properties of the Andreev interferometer shown in Fig. 6(c), which can be obtained by replacing the normal leads N1 and N2 by superconducting ones S1 and S2 in Fig. 6(a). First, we calculate I_N for several values of ε_3 and fixed $eV = 0.95\Delta$. Remarkably, as shown in Fig. 7(a), I_N takes on a hat-like shape with two maxima around phase the difference π for such values of ε_3 , where $\sigma_{N,N1}$ and $\sigma_{N,N2}$ are comparable. This is clearly different from the results in Fig. 3(a) and we are not aware of similar results in mesoscopic NS systems. Regarding I_s [Fig. 7(b)], for smaller values of ε_3 where $\sigma_{N,N1} \gg \sigma_{N,N2}$, it is qualitatively similar to the results shown in Fig. 3(b). On the other hand, the current-phase relation of I_s becomes similar to the conventional $I_s = I_c \sin \delta\phi$ as the conductive channel gradually opens between N and S2 and consequently $\sigma_{N,N1} \approx \sigma_{N,N2}$ [see e.g., the case $\varepsilon_3 = -0.50\gamma_0$ in Fig. 7(b)]. Note that in this case the $I_s(\delta\phi)$ dependence for $\delta\phi \approx \pi$ is different from the corresponding $eV = 0.94\Delta$ result shown in Fig. 3(b). In Fig. 7(c) and

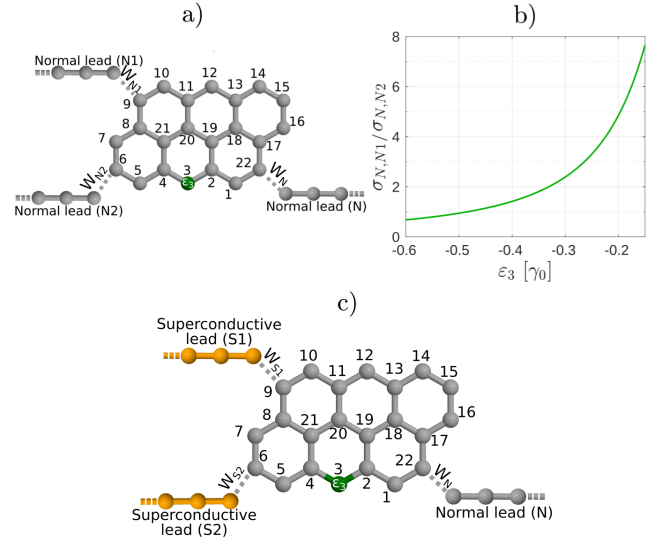


Figure 6. a) Schematics of Anthanthrene molecule with a heteroatom denoted by green. b) Ratio of the normal conductance between contacts N-N2 and N-N1 as a function of the on-site energy ε_3 in Fig. 6. At $\varepsilon_3 = 0$ the conductance $\sigma_{N,N1}$ between contacts N and N1 is much larger than the conductance $\sigma_{N,N2}$ between contacts N and N2, in agreement with Refs.^{12,30}. For finite ε_3 the conductance $\sigma_{N,N2}$ increases and can be comparable to $\sigma_{N,N1}$. c) Andreev interferometer setup obtained by replacing the normal leads N1 and N2 in a) by superconducting ones S1 and S2.

(d) we show I_N and I_s , respectively, as a function of $\delta\phi$ for several biases eV . Here we fixed $\varepsilon_3 = -0.50\gamma_0$, i.e., $\sigma_{N,N1} \approx \sigma_{N,N2}$. As one can see, for small eV , when the occupation of the ABS is not yet modified, I_N shows qualitatively the same behavior as in Fig. 5(a), i.e., when there was no current-carrying ABS in the system. For larger eV , however, there is a clear difference with respect to both Fig. 3(a) and Fig. 5(a), since I_N adopts a hat-like dependence on $\delta\phi$. The non-equilibrium population of the ABSs also affects I_s [see Fig. 7(d)] which starts to deviate from the $\propto \sin \delta\phi$ dependence for $eV > 0.95\Delta$.

According to our calculations the presence of a heteroatom does not modify the ABS spectrum significantly [Fig. 8(a)]. As shown in Fig. 8(b), when I_N nearly vanishes for $\varepsilon_3 = -0.50\gamma_0$, $\delta\phi = \pi$ [Fig. 7(a)], the differential conductance $\frac{dI_N}{deV}$ vanishes, too. According to Eq. (7), the vanishing of $\frac{dI_N}{deV}$ can be explained only if the coupling between the normal lead and the ABS vanishes. Therefore we turn our attention to the electron- and hole-like broadening terms Γ_n^e and Γ_n^h in the numerator of Eq. (7). In Figs 8(c) and (d) we show the local density of states (LDOS) on the molecular site connected to the normal contact separately for the electron- and hole-like degrees of freedom. Note that Γ_n^e and Γ_n^h are proportional to the corresponding LDOS. As one can see, the electron-like component of the LDOS becomes highly suppressed at phase difference $\delta\phi = \pi$, while the hole-like components has a maximum there. In turn, we found that on

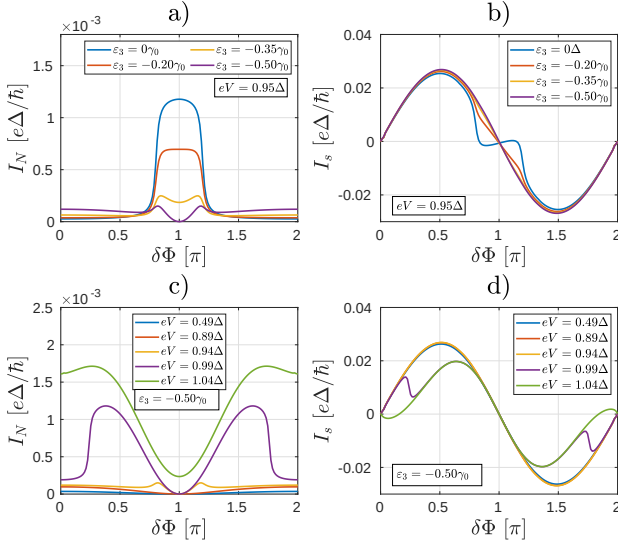


Figure 7. The currents (a) I_N and (b) I_s as a function of the phase difference $\delta\phi$ between the superconducting leads for the system depicted in Fig. 6(a) for several values of the on-site energy ϵ_3 and fixed bias $eV = 0.95\Delta$. I_N starts to show a double peak structure as a function of $\delta\phi$ for $\epsilon_3 \gtrsim -0.20\gamma_0$. (c) I_N and (d) I_s as a function of the bias voltage eV for $\epsilon_3 = -0.50\gamma_0$.

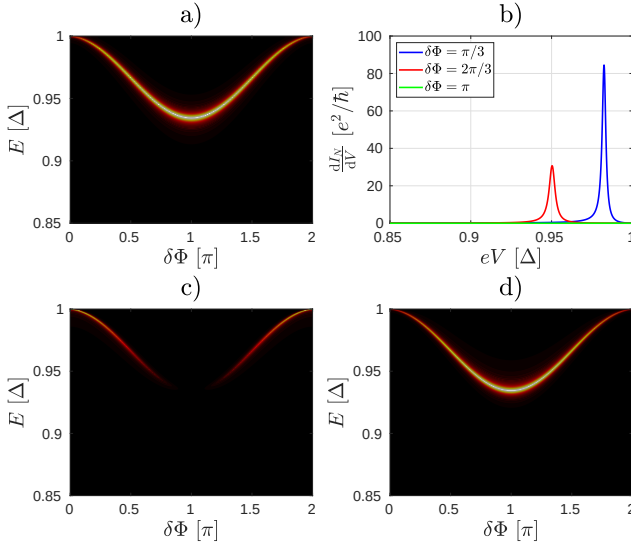


Figure 8. a) The density of states of the ABS for the case shown in Fig. 6(c). b) The differential conductance corresponding to a). The local density of states for electron (c) and hole (d) quasiparticles as a function of $\delta\Phi$. In these calculations we used $\epsilon_3 = -0.50\gamma_0$.

other sites of the molecule the hole-like component of the LDOS can be suppressed and the electron-like LDOS enhanced (an example is shown in the Supplementary information).

The surprising result in Figs. 8(c) and (d) can be understood as a peculiar interference effect that acts in a different way on the electron- and the hole-like par-

ticles. (Note, that due to electron-hole symmetry, the same feature can be observed for negative energies with a constructive interference in the electron-like part of the LDOS and with a destructive interference in the hole-like part of the LDOS.) One can give the following simple argument in terms of new quasiparticle paths. In Fig. 9 we show two quasiparticle trajectories. The first describes the process $N \rightarrow S2 \rightarrow S1 \rightarrow N$ and the last segment $S1 \rightarrow N$ is made possible by the fact that the substitutional heteroatom opened a new conductive channel. Using a similar argument as in the case of Eq. (5), one can argue that the amplitude of the path contributing to the electron-like part of the wave function can be expressed as

$$t_{\text{odd}}^e \sim M_{N,S1} \cdot e^{i\phi_1} \cdot (-M_{S1,S2}) \cdot e^{-i\phi_2} \cdot M_{S2,N} \\ \sim -M_{N,S1} \cdot M_{S1,S2} \cdot M_{S2,N} e^{i(\phi_1 - \phi_2)}. \quad (8)$$

Since t_{odd}^e contains an odd number of propagations through the molecule, and the sign of the propagation depends on whether one considers electron- or hole-like particles, the amplitude t_{odd}^h contributing to the hole-like component of the wave function would differ by a minus sign compared to t_{odd}^e . Now consider the process $N \rightarrow S2 \rightarrow S1 \rightarrow S2 \Rightarrow N$ depicted in Fig. 9(b). The last propagation indicated by $S2 \Rightarrow N$ describes a normal reflection (without electron-hole conversion) at the site connected to S2 and a forthcoming propagation to the normal contact. (Since we are working in the weak coupling limit, the normal reflection at sites connected to the contacts has a finite probability.) The amplitude corresponding to this path can be expressed as follows:

$$t_{\text{even}}^e \sim M_{N,S2} \cdot M_{S2,S1} \cdot e^{i\phi_1} \cdot (-M_{S1,S2}) \cdot e^{-i\phi_2} \cdot M_{S2,N} \\ \sim -M_{N,S2}^2 \cdot M_{S1,S2}^2 \cdot e^{i(\phi_1 - \phi_2)} \quad (9)$$

Since t_{even}^e depends on the square of the connectivity matrix elements, the corresponding hole-like amplitude t_{even}^h would have the same sign as t_{even}^e . One can see that because of the sign difference, there is a destructive interference in total amplitude $t^e = t_{\text{even}}^e + t_{\text{odd}}^e$ and a constructive one in $t^h = t_{\text{even}}^h + t_{\text{odd}}^h$. This example shows how differences can appear in the processes that determine the electron-like and the hole-like LDOS. Note that, strictly speaking, in the calculation of t^e and t^h one would need to take into account all possible scattering paths and not only those discussed above. We expect, however, that the described interference effect would not be affected significantly.

We also mention that according to our numerical results the interference effect can be swapped between the electron- and hole-like components by changing the sign of the on-site energy ϵ_3 of the heteroatom. According Eq. (8) of Ref.¹³ the connectivity matrix element $M_{N,S1}$ can change a sign for sufficiently large heteroatom on-site energy. Consequently, t_{odd}^e would also change sign resulting in a constructive interference for the electron-like and destructive interference for the hole-like components in the LDOS.

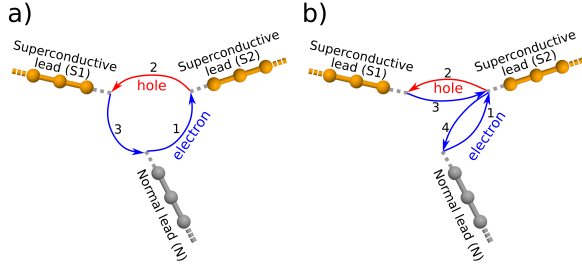


Figure 9. a) An example for interfering paths having an amplitude of opposite sign for the electron- and hole-like particles. These kinds of paths have an odd number of propagation through the molecular core. b) A representative of trajectories consisting of even number of propagations through the molecular core. The amplitude of these kinds of trajectories have the same sign for the electron- and hole-like quasiparticles.

Opening of new conductance channels can affect the properties of the molecular Andreev interferometer not only in the case discussed in Figs. 6 and 7, where the conductance between the leads N and $S1$ was tuned. As noted earlier for the system in Fig. 1, for this configuration of the leads the connectivity matrix element is zero between the two sites where the superconducting electrodes are attached. However, this connectivity matrix element can also be made finite by adding a heteroatom as indicated in Fig. 10(a). This means changing the on-site energy ϵ_{12} in the tight-binding Hamiltonian of the molecular core. We found that the dependence of the supercurrent on ϵ_{12} and eV is qualitatively similar to the behavior in Fig. 7(b) and (c). Therefore we only show the calculations for I_N in Fig. 10(b). As the connectivity grows for larger values of ϵ_{12} , the $\delta\Phi$ dependence of I_N also undergoes a drastic change and, interestingly, adopts a qualitatively similar behavior to the one shown in Fig. 7(a), i.e., there are two maxima in the current around $\delta\Phi = \pi$.

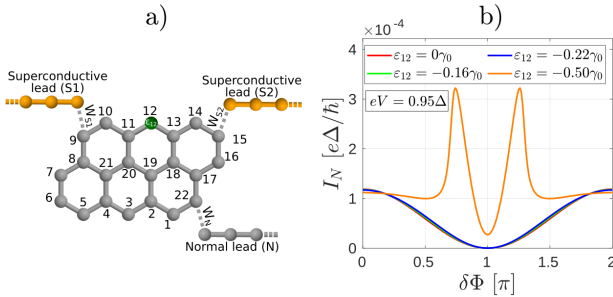


Figure 10. a) Anthanthrene molecule with a heteroatom (denoted by green) and the same configuration of leads as in Fig. 1. b) The normal current I_N as a function of the phase difference $\delta\Phi$ between the superconducting leads for the setup in (a).

CONCLUSIONS AND OUTLOOK

In this article, we have investigated the interplay between two quantum interference phenomena that take place on hugely different energy scales; QI within molecules, which takes place on the scale of electron volts and QI associated with superconductivity, which takes place on the scale of milli-electron volts. We studied the interplay between connectivity-driven QI in molecular cores and non-equilibrium charge distribution in three-terminal Andreev interferometers based on PAH molecules. We showed that QI determines certain fundamental properties of the ABS in the system, while their energies can be tuned by the phase difference between the superconducting probes. Consequently, QI and the non-equilibrium ABS occupation in the molecular core, which can be modified by a bias voltage applied to the normal lead, affects both the normal current and the supercurrent in the system. We gave a simplified explanation of some of the complicated interference effects in terms of electron and hole trajectories and point out when such explanation breaks down under non-equilibrium conditions. We found that the dependence of the normal current on the superconducting phase difference can exhibit a double-peak structure, while the supercurrent can show a π transition when the bias eV on the normal lead is larger than the superconducting gap. We also showed that adding a heteroatom to the PAH core can significantly change the QI and can induce an asymmetry in the spatial distribution of the electron- and hole-like particles, which has a direct impact on the phase dependence of the normal current. This indicates that the properties of molecular Andreev interferometers can be tuned by engineering QI in the molecular core.

For the future one may envisage a system similar to the one shown in Fig. 6 but with two normal leads ($N1$ and $N2$) attached to different sites of the molecular core. Assume now that lead $N1$ would be coupled to a site where, e.g., the electron LDOS is enhanced and the hole suppressed, whereas lead $N2$ to a site where the opposite is true, i.e., the electron LDOS is suppressed and the hole LDOS is enhanced. Then the so-called non-local Andreev reflection ($N1 \rightarrow N2$), where an incoming electron from lead $N1$ is Andreev reflected into lead $N2$, would be enhanced with respect to local Andreev reflection ($N1 \rightarrow N1$) and normal electron transmission ($N1 \rightarrow N2$). Therefore, in such four-terminal device the asymmetry between the electron- and hole-like degrees of freedom on certain sites of the molecular core could be translated into a spatial separation of electron pairs originating from the superconducting condensate. This process is called Cooper pair splitting and it provides entangled electron pairs that may play an important role in quantum information processing. Most of the proposed Cooper pair splitters to-date relied on Coulomb blockade transport through quantum dots^{53–56}, or on peculiar properties of novel low-dimensional materials^{57–59}. Our results indicate that Cooper pair splitting may also be achieved in

multi-terminal molecular systems where the spatial separation of the Cooper pairs would rely on the inner QI effects of the molecule. The detailed study of such four-terminal molecular Cooper pair splitters is an interesting problem which we leave to a future work.

ACKNOWLEDGEMENTS

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Appendix A: Theoretical background to calculate the differential conductance

In this section we give the technical details to calculate and analyze the differential conductance on the normal lead connected to an Andreev interferometer. The aim of this section is twofold. Firstly we obtain a

closed formula which can be evaluated numerically. Secondly, we answer the questions raised in the discussion of the results in Fig.3 of the main text. Namely, the reported unconventional interference effect is manifested only above a certain bias voltage applied on the normal lead. Secondly, the amplitude of the interfering path $N \rightarrow \text{mol} \rightarrow S2 \rightarrow \text{mol} \rightarrow S1 \rightarrow \text{mol} \rightarrow S2 \rightarrow \text{mol} \rightarrow N$ depicted in Fig. 3. of the main text is expected to be much smaller than the amplitude of the interfering path $N \rightarrow \text{mol} \rightarrow S2 \rightarrow \text{mol} \rightarrow N$, yet the resulting interference pattern in the Andreev current seem to be quite robust (see Fig. 4 in the main text). (The interfering path $N \rightarrow \text{mol} \rightarrow S2 \rightarrow \text{mol} \rightarrow S1 \rightarrow \text{mol} \rightarrow S2 \rightarrow \text{mol} \rightarrow N$ depicted in Fig. 3. of the main text involves four extra tunnelings between the leads and the central molecule compared to the interfering path $N \rightarrow \text{mol} \rightarrow S2 \rightarrow \text{mol} \rightarrow N$.)

The Andreev current can be evaluated using Eq. (4) of the main text. In this equation the lesser Green's function $G^<$ can be calculated within the Keldysh non-equilibrium framework using the Keldysh equation^{48–50,60,61}:

$$G^< = G^R \Sigma^< G^A, \quad (\text{A1})$$

where $G^R(E)$ [$G^A(E)$] is the retarded [advanced] Green's function and $\Sigma^<(E) = \Sigma_{S1}^<(E) + \Sigma_{S2}^<(E) + \Sigma_N^<(E, V)$ contains the lesser self energies of the leads.

The differential conductance can be derived from Eq. (4) of the main text utilizing the relation given by Eq. (A1):

$$\frac{dI_N}{deV} = -\frac{2e}{h} \text{Re} \left\{ \frac{d}{deV} \int dE \text{Tr} \left[\tau_3 W_N G^R \left(\Sigma_{S1}^< + \Sigma_{S2}^< + \Sigma_N^<(eV) \right) G^A \right] \right\} \quad (\text{A2})$$

This expression can be further simplified by applying the derivation with respect to the bias voltage V on the integrand. Notice that only the self energy of the normal

lead depends on eV . Hence

$$\frac{dI_N}{deV} = -\frac{2e}{h} \text{Re} \left\{ \int dE \text{Tr} \left[\tau_3 W_N G^R \frac{d}{deV} \Sigma_N^<(E, eV) G^A \right] \right\} \quad (\text{A3})$$

Furthermore, the lesser self energy $\Sigma_N^<(E, eV)$ depends on the bias voltage via the thermal occupation number. In the electron-hole space the lesser self energy can be given as⁴⁸

$$\Sigma_N^< = \begin{pmatrix} f_e(\Sigma_{N,e}^R - \Sigma_{N,e}^A) & 0 \\ 0 & -f_h(\Sigma_{N,h}^R - \Sigma_{N,h}^A) \end{pmatrix} \quad (\text{A4})$$

$$= \begin{pmatrix} f_e \left((g_{N,e}^A)^{-1} - (g_{N,e}^R)^{-1} \right) & 0 \\ 0 & f_h \left((g_{N,h}^A)^{-1} - (g_{N,h}^R)^{-1} \right) \end{pmatrix}, \quad (\text{A5})$$

where $f_e = f(E - eV)$ [$f_h = f(E + eV)$] is the thermal occupation number for the electrons [holes] given by the Fermi-distribution function and $\Sigma_{N,e}^R$ [$\Sigma_{N,e}^A$] and $\Sigma_{N,h}^R$ [$\Sigma_{N,h}^A$] are the retarded [advanced] self energies of the electron-like and hole-like particles in the normal lead, uncoupled from the rest of the system. Similarly, $g_{N,e/h}^R$ and $g_{N,e/h}^A$ stand for the retarded and advanced Green's

functions of the electron/hole-like particles in the normal lead. To calculate the retarded and advanced self energies and Green's functions we followed the numerical procedure described in Ref.⁶². Also, we assume the uncoupled leads to be in thermal equilibrium.

For simplicity we will consider the zero temperature limit in our calculations. Consequently, the derivative of the Fermi distribution function is the Dirac delta function and the integral in Eq. (A3) simplifies to

$$\begin{aligned} \frac{dI_N}{dV} = & -\frac{2e}{h} \text{Re} \left\{ \text{Tr} \left[\tau_3 W_N G^R(eV) \begin{pmatrix} (g_{N,e}^A(eV))^{-1} & 0 \\ 0 & (g_{N,e}^R(eV))^{-1} \end{pmatrix} G^A(eV) \right] \right\} \\ & + \frac{2e}{h} \text{Re} \left\{ \text{Tr} \left[\tau_3 W_N G^R(-eV) \begin{pmatrix} 0 & 0 \\ 0 & (g_{N,h}^A(-eV))^{-1} - (g_{N,h}^R(-eV))^{-1} \end{pmatrix} G^A(-eV) \right] \right\}. \end{aligned} \quad (\text{A6})$$

As we can see from Eq. (A6), the key element to calculate the differential conductance is the retarded and advanced Green's functions G^R and G^A . Eq. (A6) then can be directly used to calculate numerically the differential conductance in the studied three-terminal junctions.

To get further insight into the physics of the transport process we follow the logic of Ref.⁵² to evaluate these Green's functions in terms of the Dyson's equation. Let us denote the retarded Green's function of the unified system of the two superconducting contacts and the central molecular core by g_{mol}^R . Then the retarded Green's function of the whole Andreev interferometer can be eval-

uated in terms of the Dyson's equation:

$$G^R = \begin{pmatrix} (g_{\text{mol}}^R)^{-1} & -W_N^\dagger \\ -W_N & (g_N^R)^{-1} \end{pmatrix}^{-1}, \quad (\text{A7})$$

where

$$g_N^R = \begin{pmatrix} g_{N,e}^R & 0 \\ 0 & g_{N,h}^R \end{pmatrix} \quad (\text{A8})$$

is the Green's function of the normal lead containing both the electron and hole-like components. Equation (A7) yields for the individual components of the Green's function:

$$G^R = \begin{pmatrix} G_{\text{mol,mol}}^R & G_{\text{mol,N}}^R \\ G_{N,\text{mol}}^R & G_{N,N}^R \end{pmatrix} = \begin{pmatrix} g_{\text{mol}}^R (1 - W_N^\dagger g_N^R W_N g_{\text{mol}}^R)^{-1} & g_{\text{mol}}^R (1 - W_N^\dagger g_N^R W_N g_{\text{mol}}^R)^{-1} W_N^\dagger g_N^R \\ g_N^R (1 - W_N g_{\text{mol}}^R W_N^\dagger g_N^R)^{-1} W_N g_{\text{mol}}^R & g_N^R (1 - W_N g_{\text{mol}}^R W_N^\dagger g_N^R)^{-1} \end{pmatrix}. \quad (\text{A9})$$

Considering the rules of the matrix multiplication, and that the only non-zero elements of the lesser self energy of Eq. (A5) are the block diagonal parts related to the leads, in order to evaluate the differential conductance

(A6) it is enough to consider the $G_{\text{mol,N}}^R$ block of the retarded Green's function and the $G_{N,N}^A$ part of the advanced Green's function. According to the structure of Eq. (A9) one finds:

$$\begin{aligned} G_{N,N}^R &= g_N^R \sum_{n=0}^{\infty} (W_N g_{\text{mol}}^R W_N^\dagger g_N^R)^n = g_N^R + g_N^R W_N g_{\text{mol}}^R \sum_{n=0}^{\infty} (W_N g_{\text{mol}}^R W_N^\dagger g_N^R)^n W_N^\dagger g_N^R \\ &= g_N^R + g_N^R W_N g_{\text{mol}}^R (1 - W_N^\dagger g_N^R W_N g_{\text{mol}}^R)^{-1} W_N^\dagger g_N^R = g_N^R + g_N^R W_N G_{\text{mol,mol}}^R W_N^\dagger g_N^R, \end{aligned} \quad (\text{A10})$$

and

$$G_{\text{mol,N}}^R = G_{\text{mol,mol}}^R W_N^\dagger g_N^R. \quad (\text{A11})$$

We now return to the evaluation of the differential con-

ductance given by Eq. (A6). For simplicity we continue our calculations focusing on the first (electron-like) part of Eq. (A6). (Due to the electron-hole symmetry of

the Bogoliubov-de Gennes equations, the hole-like part would give the same result.) Inserting Eqs. (A10) and (A11) into Eq. (A6) yields:

$$\begin{aligned} \frac{dI_N^e}{dV} &= -\frac{2e}{h} \text{Re} \left\{ \text{Tr} \left[\tau_3 W_N G_{\text{mol},N}^R \begin{pmatrix} (g_{N,e}^A)^{-1} & 0 \\ 0 & (g_{N,e}^R)^{-1} \end{pmatrix} G_{N,N}^A \right] \right\} \\ &= -\frac{4e}{h} \text{Im} \left\{ \text{Tr} \left[\tau_3 W_N G_{\text{mol},\text{mol}}^R W_N^\dagger \begin{pmatrix} \text{Im}(g_{N,e}^R) & 0 \\ 0 & 0 \end{pmatrix} (1 + W_N G_{\text{mol},\text{mol}}^A W_N^\dagger g_N^A) \right] \right\}. \end{aligned} \quad (\text{A12})$$

In Eq. (A12) we applied the identity $g_{N,e}^R - g_{N,e}^A = 2i \text{Im}(g_{N,e}^R)$. For simplicity let's suppose we have only one Andreev bound state (ABS) formed in the superconductor – molecular core – superconductor (S-mol-S) junction described by the Green's function G_{mol}^R . In the presence of the normal lead, the ABS's starts to leak out via the normal lead resulting in the broadening of the ABS energy levels. Since our main interest are the transport properties close to the mid of the HOMO-LUMO gap, in the relevant energy regime we do not expect any further bound states in $G_{\text{mol},\text{mol}}^R$ besides the ones corresponding to the ABS's. Thus, we might approximate $G_{\text{mol},\text{mol}}^R$ as:

$$G_{\text{mol},\text{mol}}^R(E) \approx \frac{|ABS\rangle\langle ABS|}{E - E_{ABS} + i\Gamma_{ABS}}. \quad (\text{A13})$$

Here the state $|ABS\rangle$ represents the wave function of the ABS in the molecule of energy E_{ABS} , and $\Gamma_{ABS} = \langle ABS | W_N^\dagger \text{Im}(g_N^R) W_N | ABS \rangle$ is the level broadening originating from the escape rate of the particles through

the normal lead.⁵² The mathematical expression for Γ_{ABS} calculates the overlap between the ABS wave function and the self energy of the normal lead. Thus, Γ_{ABS} can be divided into two distinct terms, one related to the escape rate of the electron-like and the second one to the escape rate of the hole-like particles. Namely, $\Gamma_{ABS} = \Gamma_{ABS,e} + \Gamma_{ABS,h}$, where:

$$\Gamma_{ABS,e} = \left\langle ABS \left| W_N^\dagger \begin{pmatrix} \text{Im}(g_{N,e}^R(E_{ABS})) & 0 \\ 0 & 0 \end{pmatrix} W_N \right| ABS \right\rangle, \quad (\text{A14})$$

and

$$\Gamma_{ABS,h} = \left\langle ABS \left| W_N^\dagger \begin{pmatrix} 0 & 0 \\ 0 & \text{Im}(g_{N,h}^R(E_{ABS})) \end{pmatrix} W_N \right| ABS \right\rangle. \quad (\text{A15})$$

Using the (A13) expression of $G_{\text{mol},\text{mol}}^R$ and the invariance of the $\text{Tr}(\dots)$ function against the cyclic permutation of its arguments one obtains for the differential conductance:

$$\begin{aligned} \frac{dI_N^e}{dV} &\approx -\frac{4e}{h} \text{Im} \left\{ \frac{\left\langle ABS \left| W_N^\dagger \begin{pmatrix} \text{Im}(g_{N,e}^R) & 0 \\ 0 & 0 \end{pmatrix} W_N \right| ABS \right\rangle}{eV - E_{ABS} + i\Gamma_{ABS}} \right. \\ &\quad \left. - \frac{4e}{h} \text{Im} \left\{ \frac{\left\langle ABS \left| W_N^\dagger \begin{pmatrix} \text{Im}(g_{N,e}^R) & 0 \\ 0 & 0 \end{pmatrix} W_N \right| ABS \right\rangle}{eV - E_{ABS} + i\Gamma_{ABS}} \frac{\left\langle ABS \left| W_N^\dagger g_N^A \tau_3 W_N \right| ABS \right\rangle}{eV - E_{ABS} - i\Gamma_{ABS}} \right\} \right\}. \end{aligned} \quad (\text{A16})$$

Now making use of the definition of the broadening parameters $\Gamma_{ABS,e}$ and $\Gamma_{ABS,h}$ we end up with the following expression for the differential conductance:

$$\frac{dI_N^e}{dV} \approx \frac{8e}{h} \frac{\Gamma_{ABS,e} \Gamma_{ABS,h}}{(eV - E_{ABS})^2 + \Gamma_{ABS}^2}. \quad (\text{A17})$$

In the above expression we neglected the energy dependence of the Green's function of the normal lead in a

Γ_{ABS} wide vicinity of the energy E_{ABS} . Accounting also for the hole-like part of the differential conductance (A6) gives an additional factor of two in the final result due to the electron-hole symmetry. Thus, the total differential conductance would be given by Eq. (7) of the main text. In case we have more than one ABS in the junction, the first term of Eq. (A16) would turn into a sum of Lorentzian resonances, while the second term evolves into a more complex mathematical expression:

$$-\sum_{p,q} \text{Im} \left\{ \frac{\left\langle p \left| W_N^\dagger \begin{pmatrix} \text{Im}(g_{N,e}^R) & 0 \\ 0 & 0 \end{pmatrix} W_N \right| q \right\rangle}{eV - E_p + i\Gamma_{pp}} \frac{\left\langle q \left| W_N^\dagger g_N^A \tau_3 W_N \right| p \right\rangle}{eV - E_q - i\Gamma_{qq}} \right\} = \text{Im} \sum_{p,q} \frac{\Gamma_{pq,e}}{eV - E_p + i\Gamma_{pp}} \frac{\Gamma_{qp,e} - \Gamma_{qp,h}}{eV - E_q - i\Gamma_{qq}} \quad (\text{A18})$$

where $|q\rangle$, E_q and Γ_q represents the wave function, the energy and the broadening of the q th ABS, and the quantities $\Gamma_{qp,e}$ and $\Gamma_{qp,h}$ are defined similarly to Eqs. (A14) and (A15), but the scalar product is taken between wave functions corresponding to different ABS's. Besides reg-

ular Lorentzian resonances [$p = q$ terms of Eq. (A18)] we see that the differential conductance is heavily influenced by the cross-talk of the individual ABS's. Mathematically the product of two fractions on the right hand side of Eq. (A18) can be rewritten to a sum

$$\frac{\Gamma_{pq,e}}{eV - E_p + i\Gamma_{pp}} \frac{\Gamma_{qp,e} - \Gamma_{qp,h}}{eV - E_q - i\Gamma_{qq}} = \frac{\lambda}{eV - E_p + i\Gamma_{pp}} + \frac{\delta}{eV - E_q - i\Gamma_{qq}}, \quad (\text{A19})$$

where λ and δ are in general complex numbers. (Individually both of them have singularity at $eV = (\Gamma_{pp}E_q + \Gamma_{qq}E_p)/(\Gamma_{pp} + \Gamma_{qq})$, but these singularities cancel each other in the sum of the two fractions.) Consequently, the imaginary part of these fractions would differ from the regular Lorentzian function and the total differential conductance in the presence of multiple ABS's would be the sum of asymmetric Lorentzian resonances centered to the energies of the ABS's. The asymmetry in the resonances is a signature of the cross-talk between the ABS's.

Appendix B: Resonant oscillation

As discussed in the main text, we try to explain the unconventional interference pattern by the interplay of the two paths depicted in Fig. 2 of the main text. However the amplitude $t_{9,22}$ (defined by Eq. (1) of the main text) might be expected to be much larger than the amplitude $t_{6,22}^{(9)}$ (defined by Eq. (5) of the main text) which would suppress the interference effect between these two interfering paths.

The physical picture behind the small magnitude of $t_{6,22}^{(9)}$ relative to $t_{9,22}$ is associated to the particle transfer between the two superconducting banks. The four tunneling processes between the molecular core and the superconducting electrodes significantly decreases the magnitude of the interfering amplitude $t_{6,22}^{(9)}$. On the other hand, a resonant oscillation realized by the ABSs overwrites this physical picture. In this case the charge transport between the superconducting banks becomes resonantly amplified via the ABS and thus the amplitudes $t_{6,22}^{(9)}$ and $t_{9,22}$ becomes comparable. In summary, for energies close enough to the energy of an ABS the differential conductance shows an interference effect due to the resonant amplification of the interfering amplitude $t_{6,22}^{(9)}$, while for other energies the interference would be suppressed.

Appendix C: Density of states

In this subsection we give the technical details to calculate the density of states of the three-terminal molecular junction, which can be used to physically interpret the numerical results obtained by Eqs. (4) of the main text and by Eq. (A6). We calculate the density of states ρ from the equilibrium Green's function of the three-terminal molecular junction labeled by $G_{\text{mol,mol}}^R$ in the calculations above. To be precise, $G_{\text{mol,mol}}^R$ labels only that block of the whole Green's function which contains only the molecular degrees of freedom. Then the density of states can be defined as:

$$\rho(E) = -\frac{1}{\pi} \text{Tr} [\text{Im} (G_{\text{mol,mol}}^R(E))] . \quad (\text{C1})$$

As for the differential conductance, $G_{\text{mol,mol}}^R$ can be calculated via the Dyson's equation (A7) which is evaluated using the Eötvös Quantum Utilities (EQuUs)⁵¹ software package.

Appendix D: The tight-binding model of the molecular junctions

To describe the electrical transport processes in the studied molecular junctions we use a nearest neighbor tight binding model catching the dynamics of the p_z electrons of the molecular core. The tight binding parameters describing the molecular core are chosen following the philosophy in Refs.^{12,30}, where the aim is to highlight the role of connectivity in determining the transport properties of these molecular cores. For this reason, the hopping integrals $\gamma_{ii'} = \gamma_0$ are set to unity and the on-site energies ϵ_i are set to zero. With other words, the unit of energy is the hopping integral and the site energy is the energy origin. This means that the Hamiltonian of the molecule is simply a connectivity matrix and there-

- ¹ J. C. Cuevas and E. Scheer, *Molecular Electronics*, WORLD SCIENTIFIC, 2nd edn., 2017.
- ² M. Ratner, *Nature Nanotechnology*, 2013, **8**, 378–381.
- ³ M. Tsutsui and M. Taniguchi, *Sensors*, 2012, **12**, 7259–7298.
- ⁴ E. Lörtscher, *Nature Nanotechnology*, 2013, **8**, 381–384.
- ⁵ L. Sun, Y. A. Diaz-Fernandez, T. A. Gschneidtnr, F. Westerlund, S. Lara-Avila and K. Moth-Poulsen, *Chem. Soc. Rev.*, 2014, **43**, 7378–7411.
- ⁶ T. A. Su, M. Neupane, M. L. Steigerwald, L. Venkataraman and C. Nuckolls, *Nature Reviews Materials*, 2016, **1**, 16002.
- ⁷ D. Xiang, X. Wang, C. Jia, T. Lee and X. Guo, *Chemical Reviews*, 2016, **116**, 4318–4440.
- ⁸ M. S. Hybertsen and L. Venkataraman, *Accounts of Chemical Research*, 2016, **49**, 452–460.
- ⁹ P. Gehring, J. M. Thijssen and H. S. J. van der Zant, *Nature Reviews Physics*, 2019, **1**, 381–396.
- ¹⁰ J. Liu, X. Huang, F. Wang and W. Hong, *Accounts of Chemical Research*, 2019, **52**, 151–160.
- ¹¹ Y. Li, X. Yu, Y. Zhen, H. Dong and W. Hu, *Phys. Chem. Chem. Phys.*, 2019, **21**, 16293–16301.
- ¹² S. Sangtarash, C. Huang, H. Sadeghi, G. Sorohhov, J. Hauser, T. Wandlowski, W. Hong, S. Decurtins, S.-X. Liu and C. J. Lambert, *Journal of the American Chemical Society*, 2015, **137**, 11425–11431.
- ¹³ S. Sangtarash, H. Sadeghi and C. J. Lambert, *Nanoscale*, 2016, **8**, 13199–13205.
- ¹⁴ C. J. Lambert, *Journal of Physics: Condensed Matter*, 1993, **5**, 707–716.
- ¹⁵ V. C. Hui and C. J. Lambert, *Europhysics Letters (EPL)*, 1993, **23**, 203–209.
- ¹⁶ V. T. Petrashov, K. G. Chua, K. M. Marshall, R. S. Shaikhaidarov and J. T. Nicholls, *Phys. Rev. Lett.*, 2005, **95**, 147001.
- ¹⁷ M. Amado, A. Fornieri, G. Biasiol, L. Sorba and F. Giazotto, *Applied Physics Letters*, 2014, **104**, 242604.
- ¹⁸ B. J. van Wees, K.-M. H. Lenssen and C. J. P. M. Harmans, *Phys. Rev. B*, 1991, **44**, 470–473.
- ¹⁹ L.-F. Chang and P. F. Bagwell, *Phys. Rev. B*, 1997, **55**, 12678–12690.
- ²⁰ J. J. A. Baselmans, A. F. Morpurgo, B. J. van Wees and T. M. Klapwijk, *Nature*, 1999, **397**, 43–45.
- ²¹ J. J. A. Baselmans, T. T. Heikkilä, B. J. van Wees and T. M. Klapwijk, *Phys. Rev. Lett.*, 2002, **89**, 207002.
- ²² M. S. Crosser, J. Huang, F. Pierre, P. Virtanen, T. T. Heikkilä, F. K. Wilhelm and N. O. Birge, *Phys. Rev. B*, 2008, **77**, 014528.
- ²³ C. B. Winkelmann, N. Roch, W. Wernsdorfer, V. Bouchiat and F. Balestro, *Nature Physics*, 2009, 876–879.
- ²⁴ L. Bretheau, . . Girit, H. Pothier, D. Esteve and C. Urbina, *Nature*, 2013, **499**, 312.
- ²⁵ D. Weber and E. Scheer, *Nanotechnology*, 2017, **29**, 045703.
- ²⁶ J. O. Island, R. Gaudenzi, J. de Bruijkere, E. Burzurí, C. Franco, M. Mas-Torrent, C. Rovira, J. Veciana, T. M. Klapwijk, R. Aguado and H. S. J. van der Zant, *Phys. Rev. Lett.*, 2017, **118**, 117001.
- ²⁷ A. Kormányos, I. Grace and C. J. Lambert, *Phys. Rev. B*, 2009, **79**, 075119.
- ²⁸ C. Nappi, F. Romeo, L. Parlato, F. Di Capua, A. Aloisio and E. Sarnelli, *The Journal of Physical Chemistry C*, 2018, **122**, 11498–11504.
- ²⁹ P. Rakyta, A. Alanazy, A. Kormányos, Z. Tajkov, G. Kukucska, J. Koltai, S. Sangtarash, H. Sadeghi, J. Cserti and C. J. Lambert, *The Journal of Physical Chemistry C*, 2019, **123**, 6812–6822.
- ³⁰ Y. Geng, S. Sangtarash, C. Huang, H. Sadeghi, Y. Fu, W. Hong, T. Wandlowski, S. Decurtins, C. J. Lambert and S.-X. Liu, *Journal of the American Chemical Society*, 2015, **137**, 4469–4476.
- ³¹ C. J. Lambert, *Chem. Soc. Rev.*, 2015, **44**, 875–888.
- ³² H. Sadeghi, J. A. Mol, C. S. Lau, G. A. D. Briggs, J. Warner and C. J. Lambert, *Proceedings of the National Academy of Sciences*, 2015, **112**, 2658–2663.
- ³³ G. Sedghi, V. M. García-Suárez, L. J. Esdaile, H. L. Anderson, C. J. Lambert, S. Martín, D. Bethell, S. J. Higgins, M. Elliott, N. Bennett, J. E. Macdonald and R. J. Nichols, *Nature Nanotechnology*, 2011, **6**, 517 EP –.
- ³⁴ X. Zhao, C. Huang, M. Gulcur, A. S. Batsanov, M. Baghernejad, W. Hong, M. R. Bryce and T. Wandlowski, *Chemistry of Materials*, 2013, **25**, 4340–4347.
- ³⁵ T. A. Papadopoulos, I. M. Grace and C. J. Lambert, *Phys. Rev. B*, 2006, **74**, 193306.
- ³⁶ T. Markussen, J. Schiötz and K. S. Thygesen, *The Journal of Chemical Physics*, 2010, **132**, 224104.
- ³⁷ H. Vazquez, R. Skouta, S. Schneebeli, M. Kamenetska, R. Breslow, L. Venkataraman and M. S. Hybertsen, *Nature Nanotechnology*, 2012, **7**, 663 EP –.
- ³⁸ S. Ballmann, R. Härtle, P. B. Coto, M. Elbing, M. Mayor, M. R. Bryce, M. Thoss and H. B. Weber, *Phys. Rev. Lett.*, 2012, **109**, 056801.
- ³⁹ S. V. Aradhya, J. S. Meisner, M. Krikorian, S. Ahn, R. Parameswaran, M. L. Steigerwald, C. Nuckolls and L. Venkataraman, *Nano Letters*, 2012, **12**, 1643–1647.
- ⁴⁰ C. R. Arroyo, S. Tarkuc, R. Frisenda, J. S. Seldenthuis, C. H. M. Woerde, R. Eelkema, F. C. Grozema and H. S. J. van der Zant, *Angewandte Chemie International Edition*, 2013, **52**, 3152–3155.
- ⁴¹ C. M. Guedon, H. Valkenier, T. Markussen, K. S. Thygesen, J. C. Hummelen and S. J. van der Molen, *Nature Nanotechnology*, 2012, **7**, 305 EP –.
- ⁴² D. Z. Manrique, C. Huang, M. Baghernejad, X. Zhao, O. A. Al-Owaedi, H. Sadeghi, V. Kaliginedi, W. Hong, M. Gulcur, T. Wandlowski, M. R. Bryce and C. J. Lambert, *Nature Communications*, 2015, **6**, 6389 EP –.
- ⁴³ M. Famili, C. Jia, X. Liu, P. Wang, I. M. Grace, J. Guo, Y. Liu, Z. Feng, Y. Wang, Z. Zhao, S. Decurtins, R. Haener, Y. Huang, S.-X. Liu, C. J. Lambert and X. Duan, *Chem*, 2019, **5**, 474 – 484.
- ⁴⁴ M. L. Della Rocca, M. Chauvin, B. Huard, H. Pothier, D. Esteve and C. Urbina, *Phys. Rev. Lett.*, 2007, **99**, 127005.
- ⁴⁵ G. Nanda, J. L. Aguilera-Servin, P. Rakyta, A. Kormányos, R. Kleiner, D. Koelle, K. Watanabe, T. Taniguchi, L. M. K. Vandersypen and S. Goswami, *Nano Letters*, 2017, **17**, 3396–3401.
- ⁴⁶ A. F. Andreev, *Zh. Eksp. Teor. Fiz.*, 1964, **46**, year.
- ⁴⁷ P. F. Bagwell, *Phys. Rev. B*, 1992, **46**, 12573–12586.
- ⁴⁸ A. Cresti, R. Farchioni, G. Grosso and G. P. Parravicini, *Phys. Rev. B*, 2003, **68**, 075306.
- ⁴⁹ V.-N. Do, *Advances in Natural Sciences: Nanoscience and*

- Nanotechnology*, 2014, **5**, 033001.
- ⁵⁰ M. G. Pala, M. Governale and J. König, *New Journal of Physics*, 2007, **9**, 278–278.
- ⁵¹ Eötvös Quantum Utilities, <http://eqt.elte.hu/EQuUs/html/>.
- ⁵² N. R. Claughton, M. Leadbeater and C. J. Lambert, *Journal of Physics: Condensed Matter*, 1995, **7**, 8757–8784.
- ⁵³ S. Russo, M. Kroug, T. M. Klapwijk and A. F. Morpurgo, *Phys. Rev. Lett.*, 2005, **95**, 027002.
- ⁵⁴ L. Hofstetter, S. Csonka, J. Nygård and C. Schönenberger, *Nature*, 2009, **461**, 960–963.
- ⁵⁵ L. G. Herrmann, F. Portier, P. Roche, A. L. Yeyati, T. Kontos and C. Strunk, *Phys. Rev. Lett.*, 2010, **104**, 026801.
- ⁵⁶ L. Hofstetter, S. Csonka, A. Baumgartner, G. Fülöp, S. d’Hollosy, J. Nygård and C. Schönenberger, *Phys. Rev. Lett.*, 2011, **107**, 136801.
- ⁵⁷ J. Cayssol, *Phys. Rev. Lett.*, 2008, **100**, 147001.
- ⁵⁸ W. Chen, R. Shen, L. Sheng, B. G. Wang and D. Y. Xing, *Phys. Rev. B*, 2011, **84**, 115420.
- ⁵⁹ A. Schroer, P. G. Silvestrov and P. Recher, *Phys. Rev. B*, 2015, **92**, 241404.
- ⁶⁰ C. J. Bolech and T. Giamarchi, *Phys. Rev. B*, 2005, **71**, 024517.
- ⁶¹ S.-T. Wu and S. Yip, *Phys. Rev. B*, 2004, **70**, 104511.
- ⁶² I. Rungger and S. Sanvito, *Phys. Rev. B*, 2008, **78**, 035407.